

Micropower Voltage Reference Diodes

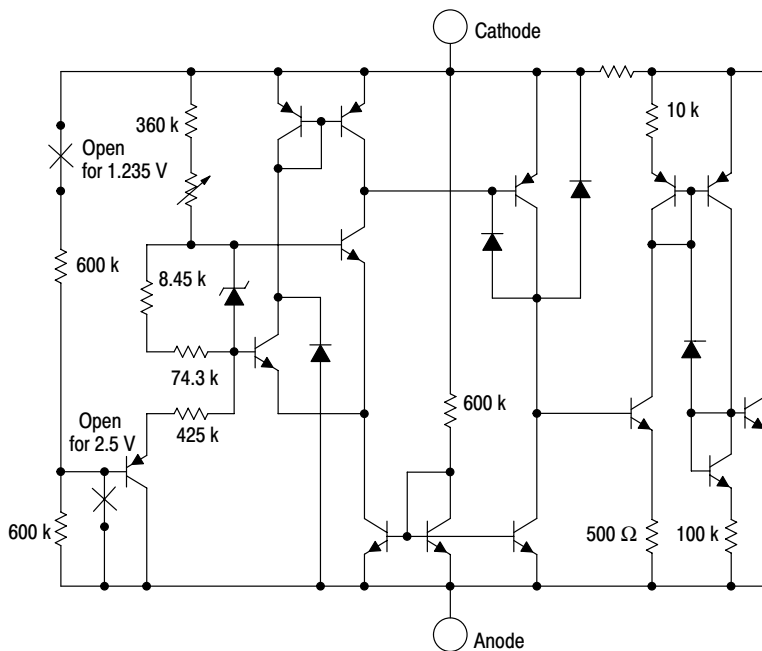
The LM285/LM385 series are micropower two-terminal bandgap voltage regulator diodes. Designed to operate over a wide current range of 10 μ A to 20 mA, these devices feature exceptionally low dynamic impedance, low noise and stable operation over time and temperature. Tight voltage tolerances are achieved by on-chip trimming. The large dynamic operating range enables these devices to be used in applications with widely varying supplies with excellent regulation. Extremely low operating current make these devices ideal for micropower circuitry like portable instrumentation, regulators and other analog circuitry where extended battery life is required.

The LM285/LM385 series are packaged in a low cost TO-226AA plastic case and are available in two voltage versions of 1.235 and 2.500 V as denoted by the device suffix (see Ordering Information table). The LM285 is specified over a -40°C to $+85^{\circ}\text{C}$ temperature range while the LM385 is rated from 0°C to $+70^{\circ}\text{C}$.

The LM385 is also available in a surface mount plastic package in voltages of 1.235 and 2.500 V.

- Operating Current from 10 μ A to 20 mA
- 1.0%, 1.5%, 2.0% and 3.0% Initial Tolerance Grades
- Low Temperature Coefficient
- 1.0 Ω Dynamic Impedance
- Surface Mount Package Available

Representative Schematic Diagram

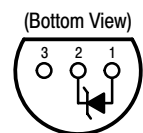


LM285 LM385, B

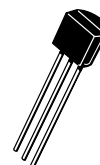
MICROPOWER VOLTAGE REFERENCE DIODES

SEMICONDUCTOR TECHNICAL DATA

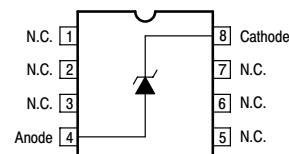
Z SUFFIX
PLASTIC PACKAGE
CASE 29



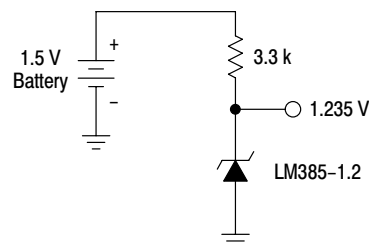
N.C.
Cathode
Anode



D SUFFIX
PLASTIC PACKAGE
CASE 751
(SO-8)



Standard Application



ORDERING INFORMATION

Device	Operating Temperature Range	Reverse Break-down Voltage	Tolerance
LM285D-1.2 LM285Z-1.2	$T_A = -40^{\circ}$ to $+85^{\circ}\text{C}$	1.235 V	$\pm 1.0\%$
LM285D-2.5 LM285Z-2.5		2.500 V	$\pm 1.5\%$
LM385BD-1.2 LM385BZ-1.2	$T_A = 0^{\circ}$ to $+70^{\circ}\text{C}$	1.235 V	$\pm 1.0\%$
LM385D-1.2 LM385Z-1.2		1.235 V	$\pm 2.0\%$
LM385BD-2.5 LM385BZ-2.5		2.500 V	$\pm 1.5\%$
LM385D-2.5 LM385Z-2.5		2.500 V	$\pm 3.0\%$

LM285 LM385, B

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Current	I_R	30	mA
Forward Current	I_F	10	mA
Operating Ambient Temperature Range LM285 LM385	T_A	- 40 to + 85 0 to +70	$^\circ\text{C}$
Operating Junction Temperature	T_J	+ 150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Characteristic	Symbol	LM285-1.2			LM385-1.2/LM385B-1.2			Unit
		Min	Typ	Max	Min	Typ	Max	
Reverse Breakdown Voltage ($I_{Rmin} \leq I_R \leq 20 \text{ mA}$) LM285-1.2/LM385B-1.2 $T_A = T_{low} \text{ to } T_{high}$ (Note 1) LM385-1.2 $T_A = T_{low} \text{ to } T_{high}$ (Note 1)	$V_{(BR)R}$	1.223 1.200 - -	1.235 - - -	1.247 1.270 - -	1.223 1.210 1.205 1.192	1.235 - 1.235 -	1.247 1.260 1.260 1.273	V
Minimum Operating Current $T_A = 25^\circ\text{C}$ $T_A = T_{low} \text{ to } T_{high}$ (Note 1)	I_{Rmin}	- -	8.0 -	10 20	- -	8.0 -	15 20	μA
Reverse Breakdown Voltage Change with Current $I_{Rmin} \leq I_R \leq 1.0 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low} \text{ to } T_{high}$ (Note 1) $1.0 \text{ mA} \leq I_R \leq 20 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low} \text{ to } T_{high}$ (Note 1)	$\Delta V_{(BR)R}$	- - - -	- - - -	1.0 1.5 10 20	- - - -	- - - -	1.0 1.5 20 25	mV
Reverse Dynamic Impedance $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C}$	Z	-	0.6	-	-	0.6	-	W
Average Temperature Coefficient $10 \mu\text{A} \leq I_R \leq 20 \text{ mA}$, $T_A = T_{low} \text{ to } T_{high}$ (Note 1)	$\Delta V_{(BR)}/\Delta T$	-	80	-	-	80	-	ppm/ $^\circ\text{C}$
Wideband Noise (RMS) $I_R = 100 \mu\text{A}$, $10 \text{ Hz} \leq f \leq 10 \text{ kHz}$	n	-	60	-	-	60	-	μV
Long Term Stability $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C} \pm 0.1^\circ\text{C}$	S	-	20	-	-	20	-	ppm/ kHR

LM285 LM385, B

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Characteristic	Symbol	LM285-2.5			LM385-2.5/LM385B-2.5			Unit
		Min	Typ	Max	Min	Typ	Max	
Reverse Breakdown Voltage ($I_{Rmin} \leq I_R \leq 20 \text{ mA}$) LM285-2.5/LM385B-2.5 $T_A = T_{low}$ to T_{high} (Note 1) LM385-2.5 $T_A = T_{low}$ to T_{high} (Note 1)	$V_{(BR)R}$	2.462 2.415 – –	2.5 – – –	2.538 2.585 – –	2.462 2.436 2.425 2.400	2.5 – 2.5 –	2.538 2.564 2.575 2.600	V
Minimum Operating Current $T_A = 25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1)	I_{Rmin}	– –	13 –	20 30	– –	13 –	20 30	μA
Reverse Breakdown Voltage Change with Current $I_{Rmin} \leq I_R \leq 1.0 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1) $1.0 \text{ mA} \leq I_R \leq 20 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 1)	$\Delta V_{(BR)R}$	– – – –	– – – –	1.0 1.5 10 20	– – – –	– – – –	2.0 2.5 20 25	mV
Reverse Dynamic Impedance $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C}$	Z		0.6	–	–	0.6	–	W
Average Temperature Coefficient $20 \mu\text{A} \leq I_R \leq 20 \text{ mA}$, $T_A = T_{low}$ to T_{high} (Note 1)	$\Delta V_{(BR)R}/\Delta T$	–	80	–	–	80	–	ppm/ $^\circ\text{C}$
Wideband Noise (RMS) $I_R = 100 \mu\text{A}$, $10 \text{ Hz} \leq f \leq 10 \text{ kHz}$	n	–	120	–	–	120	–	μV
Long Term Stability $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C} \pm 0.1^\circ\text{C}$	S	–	20	–	–	20	–	ppm/ kHR

NOTES: 1. $T_{low} = -40^\circ\text{C}$ for LM285-1.2, LM285-2.5
 $= 0^\circ\text{C}$ for LM385-1.2, LM385B-1.2, LM385-2.5, LM385B-2.5

$T_{high} = +85^\circ\text{C}$ for LM285-1.2, LM285-2.5
 $= +70^\circ\text{C}$ for LM385-1.2, LM385B-1.2, LM385-2.5, LM385B-2.5

LM285 LM385, B

TYPICAL PERFORMANCE CURVES FOR LM285-1.2/385-1.2/385B-1.2

Figure 1. Reverse Characteristics

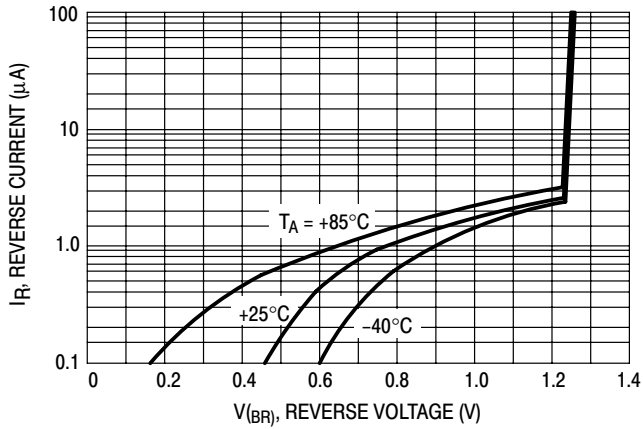


Figure 2. Reverse Characteristics

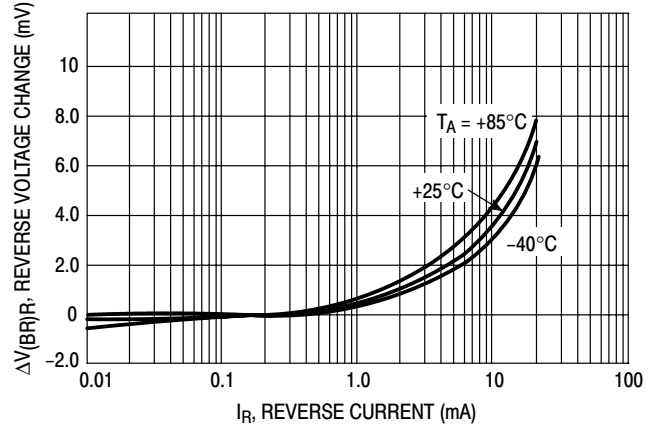


Figure 3. Forward Characteristics

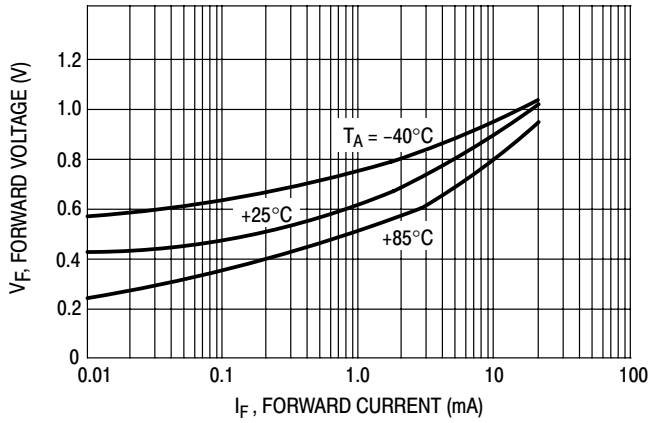


Figure 4. Temperature Drift

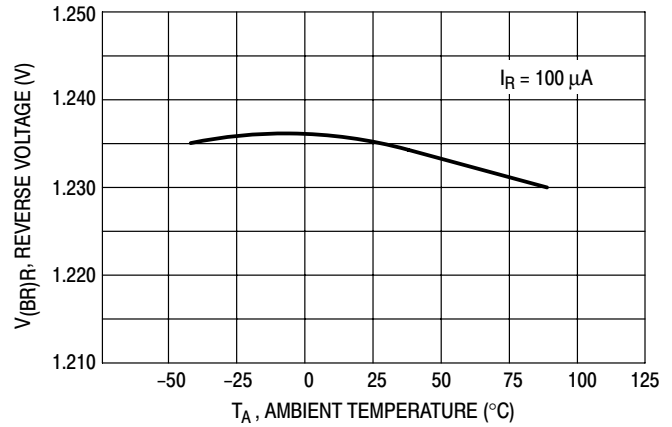


Figure 5. Noise Voltage

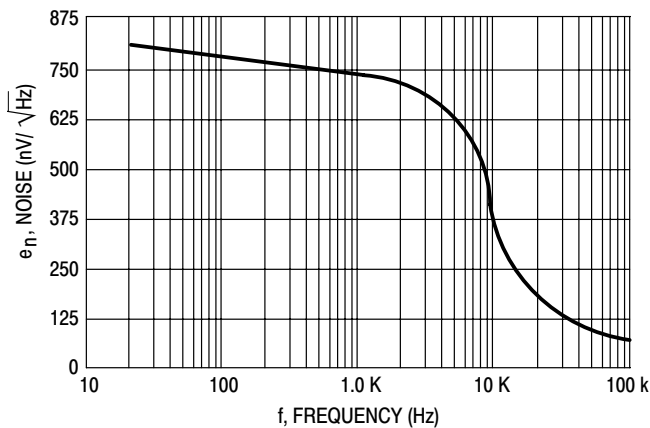
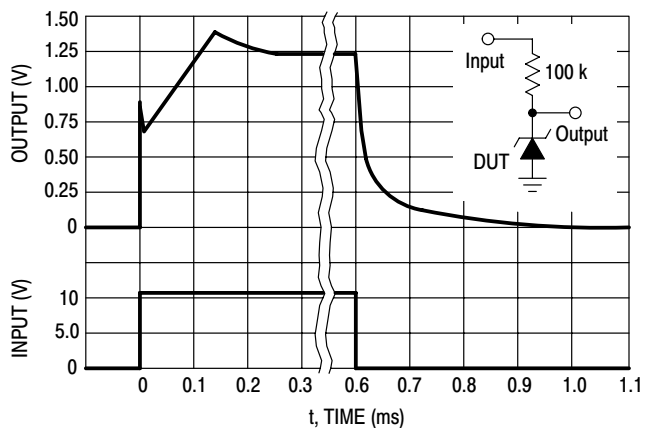


Figure 6. Response Time



LM285 LM385, B

TYPICAL PERFORMANCE CURVES FOR LM285-2.5/385-2.5/385B-2.5

Figure 7. Reverse Characteristics

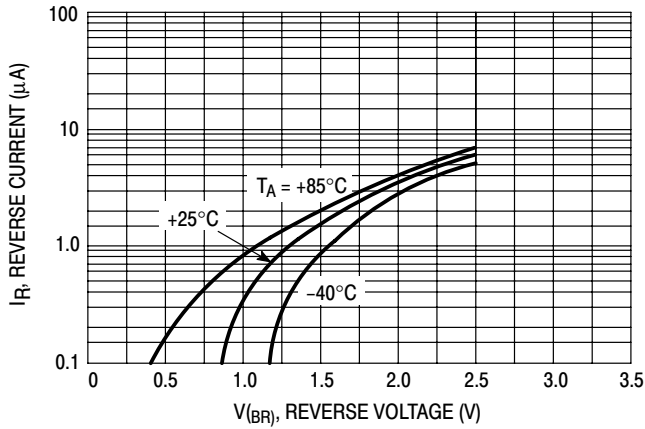


Figure 8. Reverse Characteristics

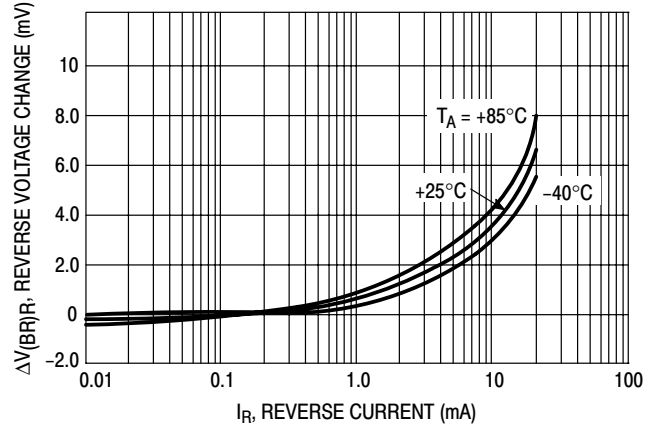


Figure 9. Forward Characteristics

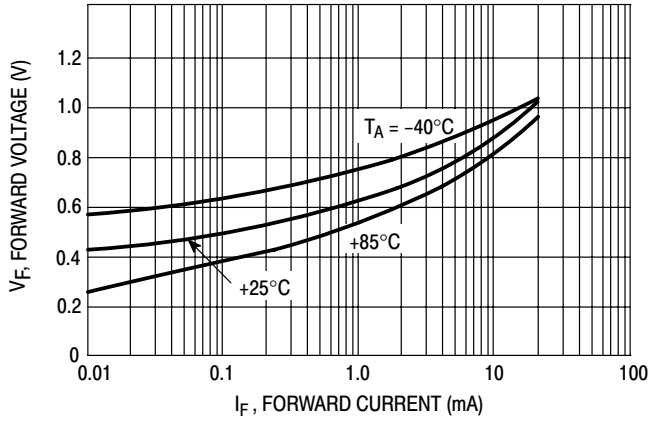


Figure 10. Temperature Drift

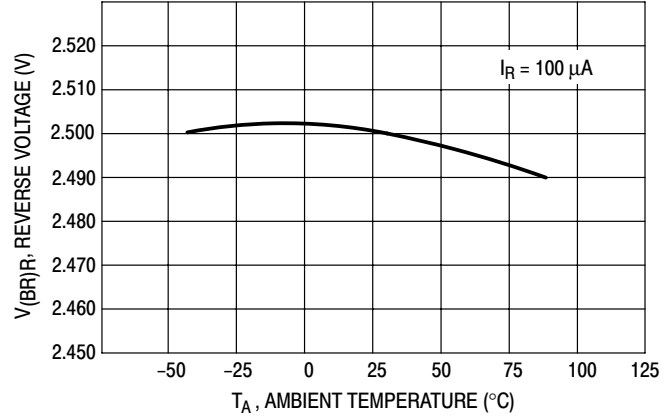


Figure 11. Noise Voltage

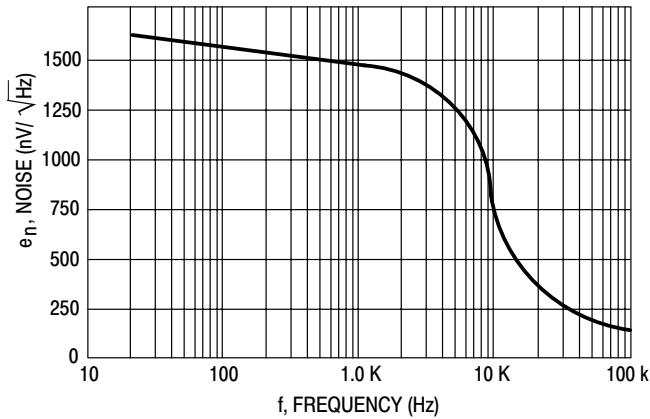
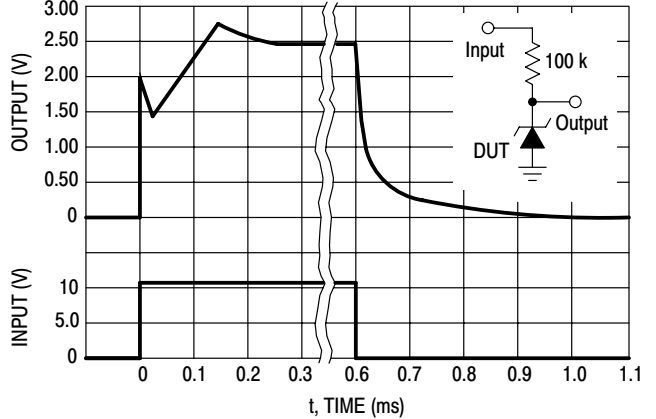


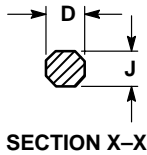
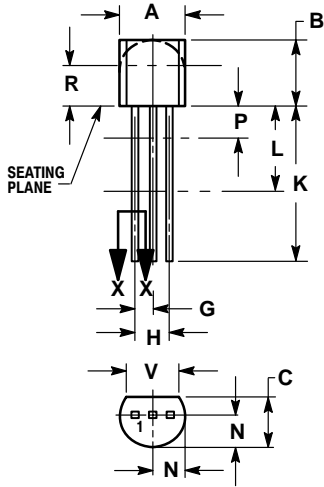
Figure 12. Response Time



LM285 LM385, B

PACKAGE DIMENSIONS

Z SUFFIX PLASTIC PACKAGE CASE 29-11 ISSUE AL

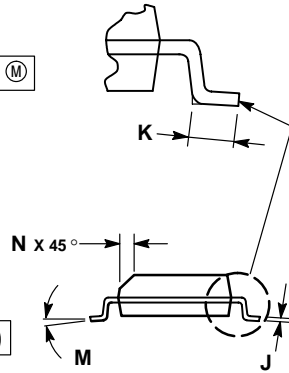
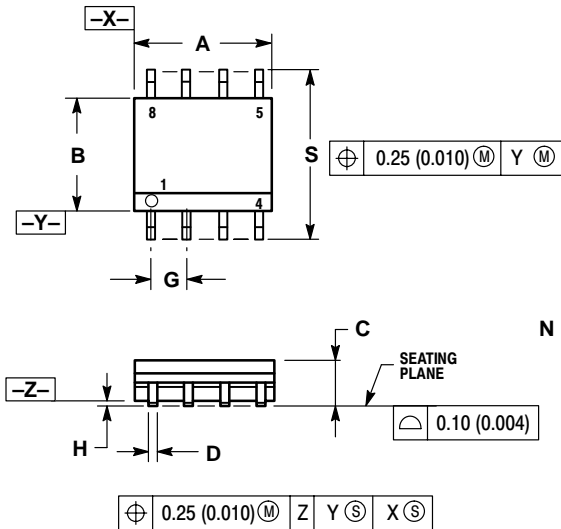


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

D SUFFIX PLASTIC PACKAGE CASE 751-07 (SO-8) ISSUE W




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

Notes

LM285 LM385, B

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